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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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# RGW60TS65

### 650V 30A Field Stop Trench IGBT

V <sub>CES</sub>	650V
I <sub>C (100°C)</sub>	30A
V <sub>CE(sat) (Typ.)</sub>	1.5V
$P_D$	178W

### ● Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

### Applications

**PFC** 

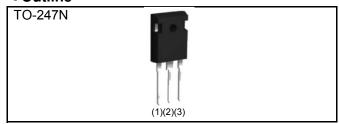
**UPS** 

Welding

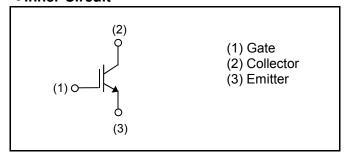
Solar Inverter

ΙH

#### Outline



### ●Inner Circuit



Packaging Specifications

	Packaging	Tube	
	Reel Size (mm)	-	
Typo	Tape Width (mm)	-	
Туре	Basic Ordering Unit (pcs)	450	
	Packing Code	C11	
Marking		RGW60TS65	

### ● Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		$V_{CES}$	650	V
Gate - Emitter Voltage		$V_{GES}$	±30	V
Collector Current	T <sub>C</sub> = 25°C	I <sub>C</sub>	60	А
Collector Current	T <sub>C</sub> = 100°C	I <sub>C</sub> 30		А
Pulsed Collector Current		I <sub>CP</sub> *1	120	А
Power Discination	T <sub>C</sub> = 25°C	P <sub>D</sub>	178	W
Power Dissipation	T <sub>C</sub> = 100°C	P <sub>D</sub>	89	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

<sup>\*1</sup> Pulse width limited by T<sub>imax</sub>.

### ●Thermal Resistance

Parameter	Symbol	Values			Unit
- Faranietei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.84	°C/W

## ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Linit
	Syllibol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_C = 10 \mu A, V_{GE} = 0 V$	650	-	-	V
Collector Cut - off Current	I <sub>CES</sub>	V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V	1	-	10	μΑ
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 20.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_C = 30A$ , $V_{GE} = 15V$ $T_j = 25$ °C $T_j = 175$ °C	-	1.5 1.85	1.9 -	V

## ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Daramatar	Cymphal	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V	-	2530	-	
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V	-	65	-	pF
Reverse Transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	46	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V	-	84	-	
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 30A	-	17	-	nC
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	31	-	
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 30A, V <sub>CC</sub> = 400V	-	37	-	
Rise Time	t <sub>r</sub>	$V_{GE} = 15V, R_G = 10\Omega$	-	13	-	
Turn - off Delay Time	t <sub>d(off)</sub>	T <sub>j</sub> = 25°C	-	114	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	35	-	
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> includes diode	-	0.48	-	
Turn - off Switching Loss	E <sub>off</sub>	reverse recovery	-	0.49	-	mJ
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 30A, V <sub>CC</sub> = 400V	-	36	-	
Rise Time	t <sub>r</sub>	$V_{GE} = 15V, R_G = 10\Omega$	-	14	-	no
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 175°C	-	133	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	76	-	
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> includes diode	-	0.49	-	
Turn - off Switching Loss	E <sub>off</sub>	reverse recovery	-	0.63	-	mJ
		I <sub>C</sub> = 120A, V <sub>CC</sub> = 520V				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650V, V_{GE} = 15V$	FU	LL SQUA	RE	-
1		$R_G = 100\Omega, T_j = 175^{\circ}C$				

### **●Electrical Characteristic Curves**

Fig.1 Power Dissipation vs. Case Temperature

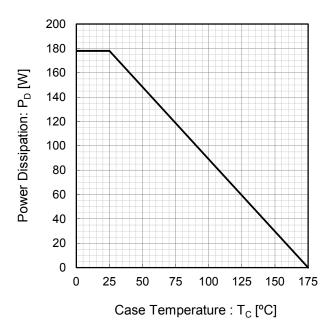


Fig.2 Collector Current vs. Case Temperature

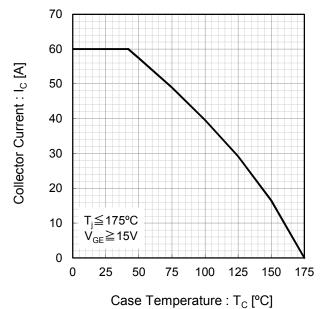


Fig.3 Forward Bias Safe Operating Area

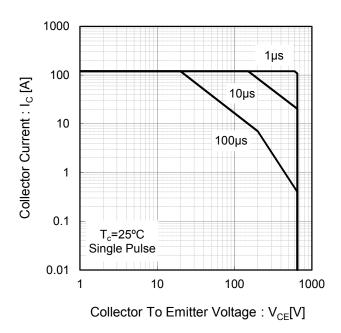
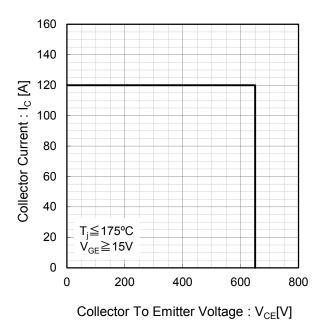


Fig.4 Reverse Bias Safe Operating Area



### • Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

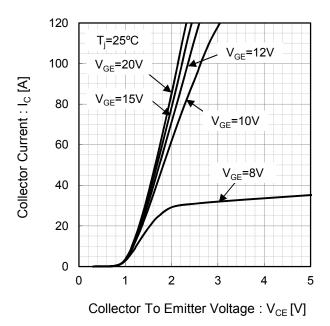
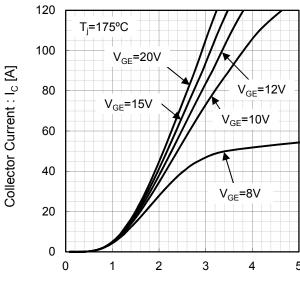


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : V<sub>CE</sub> [V]

Fig.7 Typical Transfer Characteristics

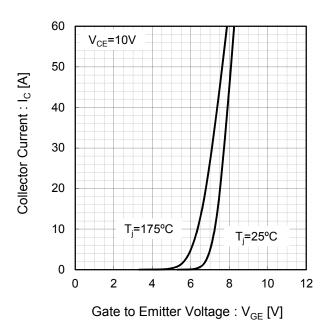
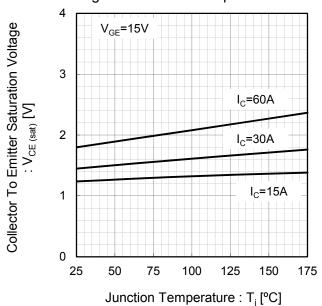
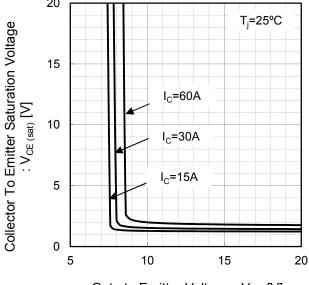


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



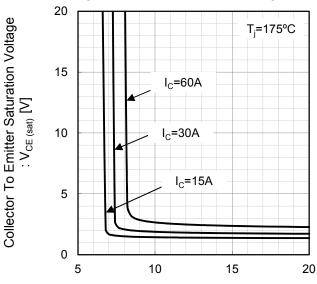
### • Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate to Emitter Voltage :  $V_{GE}[V]$ 

Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate to Emitter Voltage : V<sub>GE</sub> [V]

Fig.11 Typical Switching Time vs. Collector Current

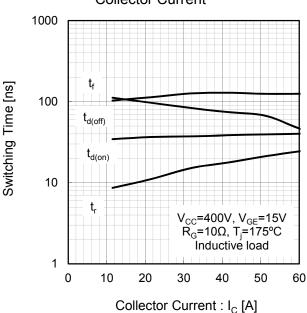
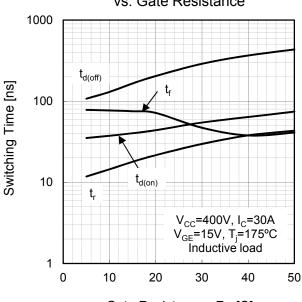


Fig.12 Typical Switching Time vs. Gate Resistance



### **•**Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs.
Collector Current

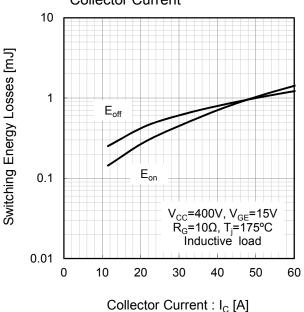


Fig.14 Typical Switching Energy Losses vs. Gate Resistance

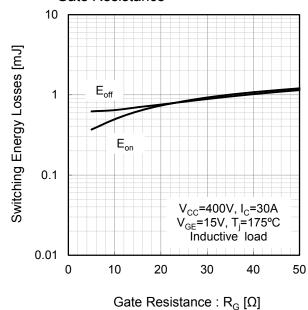
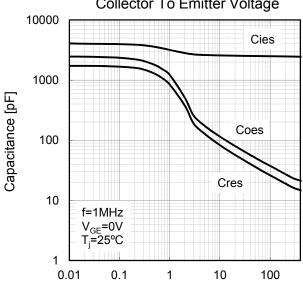
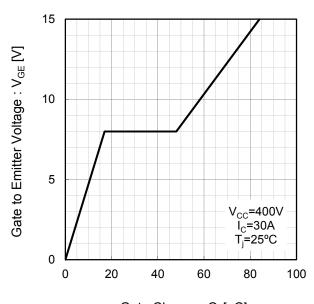


Fig.15 Typical Capacitance vs.
Collector To Emitter Voltage



Collector To Emitter Voltage :  $V_{CE}[V]$ 

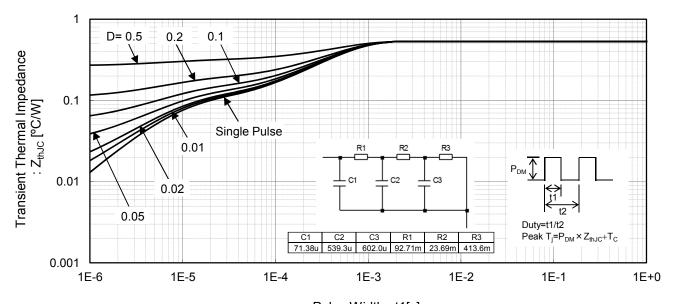
Fig.16 Typical Gate Charge



Gate Charge : Q<sub>q</sub>[nC]

### • Electrical Characteristic Curves

Fig.17 Typical IGBT Transient Thermal Impedance



Pulse Width: t1[s]

### •Inductive Load Switching Circuit and Waveform

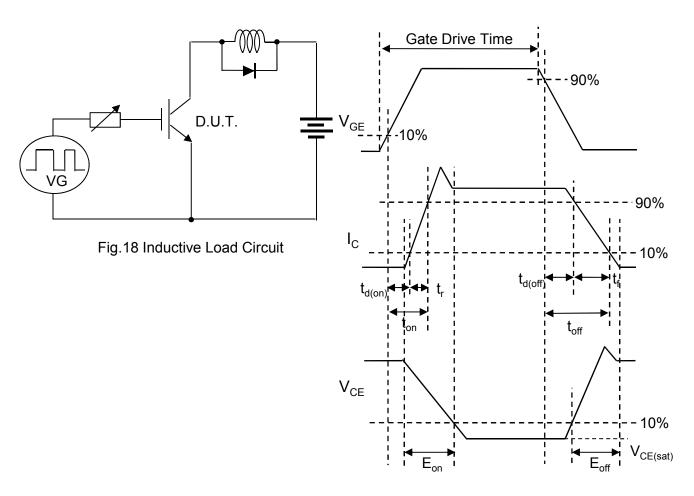


Fig.19 Inductive Load Waveform

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# RGW60TS65 - Web Page

Part Number	RGW60TS65
Package	TO-247N
Unit Quantity	450
Minimum Package Quantity	30
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes